

Low-Voltage Octal Buffer/Line Driver with 5 V Tolerant Inputs and Outputs

74LCX541



SOIC-20 WB
DW SUFFIX
CASE 751D



TSSOP-20
DT SUFFIX
CASE 948E

The LCX541 is an octal buffer/line driver designed to be employed as memory and address drivers, clock drivers and bus oriented transmitter/receivers. The LCX541 is a non-inverting option of the LCX540.

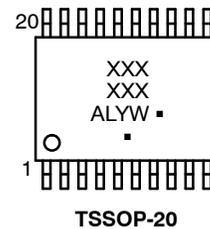
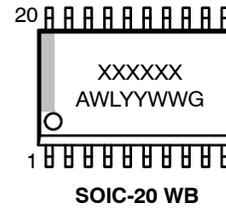
This device is similar in function to the LCX244 while providing flow-through architecture (inputs on opposite side from outputs). This pinout arrangement makes this device especially useful as an output port for microprocessors, allowing ease of layout and greater PC board density.

The LCX541 is designed for low voltage applications with capability of interfacing to a 5 V signal environment. The LCX541 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5 V Tolerant Input and Outputs
- 1.65 V–5.5 V V_{CC} Specifications Provided
- 6.5 ns t_{PD} Max. ($V_{CC} = 3.3$ V), 10 μ A I_{CC} Max.
- Power-down High Impedance Inputs and Outputs
- Supports Live Insertion/Withdrawal
- ± 24 mA Output Drive ($V_{CC} = 3.0$ V)
- Implements Proprietary Noise/ EMI Reduction Circuitry
- Latch-up Performance Exceeds JEDEC 78 Conditions
- ESD Performance
 - ◆ Human Body Model > 2000 V
- Pb-Free DQFN Package
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MARKING DIAGRAM



- A = Assembly Location
- L, WL = Wafer Lot
- Y, YY = Year
- W, WW = Work Week
- G or ■ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information on page 7 of this data sheet.

Connection Diagrams

Pin Assignments for SOIC, SOP, SSOP, TSSOP

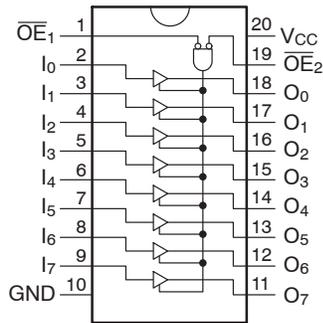


Figure 1.

Logic Symbol

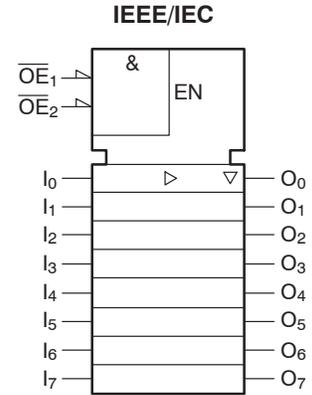
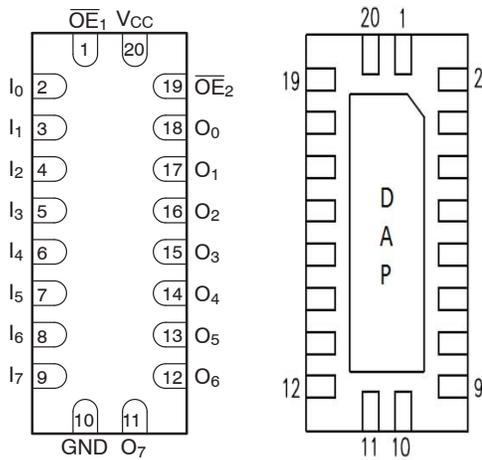


Figure 2.

Pad Assignment for DQFN



(Top View)

(Bottom View)

Figure 3.

PIN DESCRIPTION

Pin	Description
$\overline{OE}_1, \overline{OE}_2$	3-STATE Output Enable Inputs
I_0-I_7	Inputs
O_0-O_7	Outputs
DAP	No Connect

TRUTH TABLE

Inputs			Outputs
\overline{OE}_1	\overline{OE}_2	I_n	O_n
L	L	H	H
H	X	X	Z
X	H	X	Z
L	L	L	L

H = High Voltage Level
 L = Low Voltage Level
 X = Immaterial
 Z = High Impedance State

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MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	DC Supply Voltage	-0.5 to +6.5	V
V _I	DC Input Voltage (Note 1)	-0.5 to +6.5	V
V _O	DC Output Voltage (Note 1) Active-Mode (High or Low State) Tri-State Mode Power-Down Mode (V _{CC} = 0 V)	-0.5 to V _{CC} +0.5 -0.5 to +6.5 -0.5 to +6.5	V
I _{IK}	DC Input Diode Current V _{IN} < GND	-50	mA
I _{OK}	DC Output Diode Current V _{OUT} < GND	-50	mA
I _O	DC Output Source/Sink Current	±50	mA
I _{CC} or I _{GND}	DC Supply Current per Supply Pin or Ground Pin	±100	mA
T _{STG}	Storage Temperature Range	-65 to +150	°C
T _L	Lead Temperature, 1 mm from Case for 10 secs	260	°C
T _J	Junction Temperature Under Bias	+150	°C
θ _{JA}	Thermal Resistance (Note 2) SOIC-20W WQFN20 TSSOP-20	96 99 150	°C/W
P _D	Power Dissipation in Still Air SOIC-20W WQFN20 TSSOP-20	1302 1256 833	mW
MSL	Moisture Sensitivity SOIC-20W All Other Packages	Level 3 Level 1	-
F _R	Flammability Rating Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	-
V _{ESD}	ESD Withstand Voltage (Note 3) Human Body Model Charged Device Model	2000 N/A	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. I_O absolute maximum rating must be observed.
2. Measured with minimum pad spacing on an FR4 board, using 76 mm-by-114 mm, 2-ounce copper trace no air flow per JESD51-7.
3. HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A.

RECOMMENDED OPERATING CONDITIONS (Note 4)

Symbol	Parameter	Min	Max	Unit
V _{CC}	Supply Voltage Operating Data Retention Only	1.65 1.5	5.5 5.5	V
V _I	Digital Input Voltage	0	5.5	V
V _O	Output Voltage Active Mode (High or Low State) Tri-State Mode Power Down Mode (V _{CC} = 0 V)	0 0 0	V _{CC} 5.5 5.5	V
T _A	Operating Free-Air Temperature	-40	+125	°C
t _r , t _f	Input Rise or Fall Rate V _{CC} = 1.65 V to 1.95 V V _{CC} = 2.3 V to 2.7 V V _{IN} from 0.8 V to 2.0 V, V _{CC} = 3.0 V V _{CC} = 4.5 V to 5.5 V	0 0 0 0	20 20 10 5	nS/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

4. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

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DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Conditions	V _{CC} (V)	T _A = -40 °C to +85 °C		T _A = -40 °C to +125 °C		Unit
				Min	Max	Min	Max	
V _{IH}	High-Level Input Voltage		1.65 to 1.95	0.65 x V _{CC}		0.65 x V _{CC}		V
			2.3 to 2.7	1.7		1.7		
			2.7 to 3.6	2.0		2.0		
			4.5 to 5.5	0.7 x V _{CC}		0.7 x V _{CC}		
V _{IL}	Low-Level Input Voltage		1.65 to 1.95		0.35 x V _{CC}		0.35 x V _{CC}	V
			2.3 to 2.7		0.7		0.7	
			2.7 to 3.6		0.8		0.8	
			4.5 to 5.5		0.3 x V _{CC}		0.3 x V _{CC}	
V _{OH}	High-Level Output Voltage	V _I = V _{IH} or V _{IL}						V
		I _{OH} = -100 μA	1.65 to 5.5	V _{CC} - 0.1		V _{CC} - 0.1		
		I _{OH} = -4 mA	1.65	1.2		1.2		
		I _{OH} = -8 mA	2.3	1.8		1.8		
		I _{OH} = -12 mA	2.7	2.2		2.2		
		I _{OH} = -16 mA	3.0	2.4		2.4		
		I _{OH} = -24 mA	3.0	2.2		2.2		
V _{OL}	Low-Level Output Voltage	V _I = V _{IH} or V _{IL}						V
		I _{OL} = 100 μA	1.65 to 5.5		0.1		0.1	
		I _{OL} = 4 mA	1.65		0.45		0.45	
		I _{OL} = 8 mA	2.3		0.6		0.6	
		I _{OL} = 12 mA	2.7		0.4		0.4	
		I _{OL} = 16 mA	3.0		0.4		0.4	
		I _{OL} = 24 mA	3.0		0.55		0.55	
I _I	Input Leakage Current	V _I = 0 to 5.5 V	3.6		±5.0		±5.0	μA
I _{OZ}	3-State Output Leakage Current	V _I = V _{IH} or V _{IL} , V _O = 0 V to 5.5 V	3.6		±5.0		±5.0	μA
I _{OFF}	Power Off Leakage Current	V _I = 5.5 V or V _O = 5.5 V	0		10		10	μA
I _{CC}	Quiescent Supply Current	V _I = 5.5 V or GND	2.3 to 3.6		10		10	μA
ΔI _{CC}	Increase in I _{CC} per Input	V _{IH} = V _{CC} - 0.6 V	2.3 to 3.6		500		500	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

5. Outputs disabled or 3-STATE only.

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AC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test Condition	V _{CC} (V)	T _A = -40 °C to +85 °C		T _A = -40 °C to +125 °C		Unit
				Min	Max	Min	Max	
t _{PLH} , t _{PHL}	Propagation Delay, D to O	See Figures 4 and 5	1.65 to 1.95		10.3		10.3	ns
			2.3 to 2.7		7.8		7.8	
			2.7		7.5		7.5	
			3.0 to 3.6		6.5		6.5	
			4.5 to 5.5		5.9		5.9	
t _{PZH} , t _{PZL}	Output Enable Time, \overline{OE} to O	See Figures 4 and 5	1.65 to 1.95		13.0		13.0	ns
			2.3 to 2.7		10.5		10.5	
			2.7		9.5		9.5	
			3.0 to 3.6		8.5		8.5	
			4.5 to 5.5		7.3		7.3	
t _{PHZ} , t _{PLZ}	Output Disable Time, \overline{OE} to O	See Figures 4 and 5	1.65 to 1.95		11.0		11.0	ns
			2.3 to 2.7		9.0		9.0	
			2.7		8.5		8.5	
			3.0 to 3.6		7.5		7.5	
			4.5 to 5.5		6.5		6.5	
t _{OSSL} , t _{OSLH}	Output to Output Skew (Note 6)		1.65 to 1.95				ns	
			2.3 to 2.7					
			2.7					
			3.0 to 3.6		1.0			1.0

6. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the dynamic operating current consumption without load. Average operating current can be obtained by the equation I_{CC(OPR)} = C_{PD} × V_{CC} × f_{in} + I_{CC}. C_{PD} is used to determine the no-load dynamic power consumption: P_D = C_{PD} × V_{CC}² × f_{in} + I_{CC} × V_{CC}.

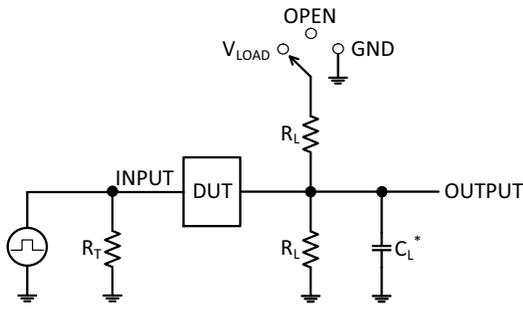
DYNAMIC SWITCHING CHARACTERISTICS

Symbol	Parameter	V _{CC} (V)	Conditions	T _A = 25 °C	Unit
				Typ	
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	3.3	C _L = 50 pF, V _{IH} = 3.3 V, V _{IL} = 0 V	0.8	V
		2.5	C _L = 30 pF, V _{IH} = 2.5 V, V _{IL} = 0 V	0.6	
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	3.3	C _L = 50 pF, V _{IH} = 3.3 V, V _{IL} = 0 V	-0.8	V
		2.5	C _L = 30 pF, V _{IH} = 2.5 V, V _{IL} = 0 V	-0.6	

CAPACITANCE

Symbol	Parameter	Conditions	Typ	Unit
C _{IN}	Input Capacitance	V _{CC} = Open, V _I = 0 V or V _{CC}	7.0	pF
C _{OUT}	Output Capacitance	V _{CC} = 3.3 V, V _I = 0 V or V _{CC}	8.0	pF
C _{PD}	Power Dissipation Capacitance	V _{CC} = 3.3 V, V _I = 0 V or V _{CC} , f = 10 MHz	25.0	pF

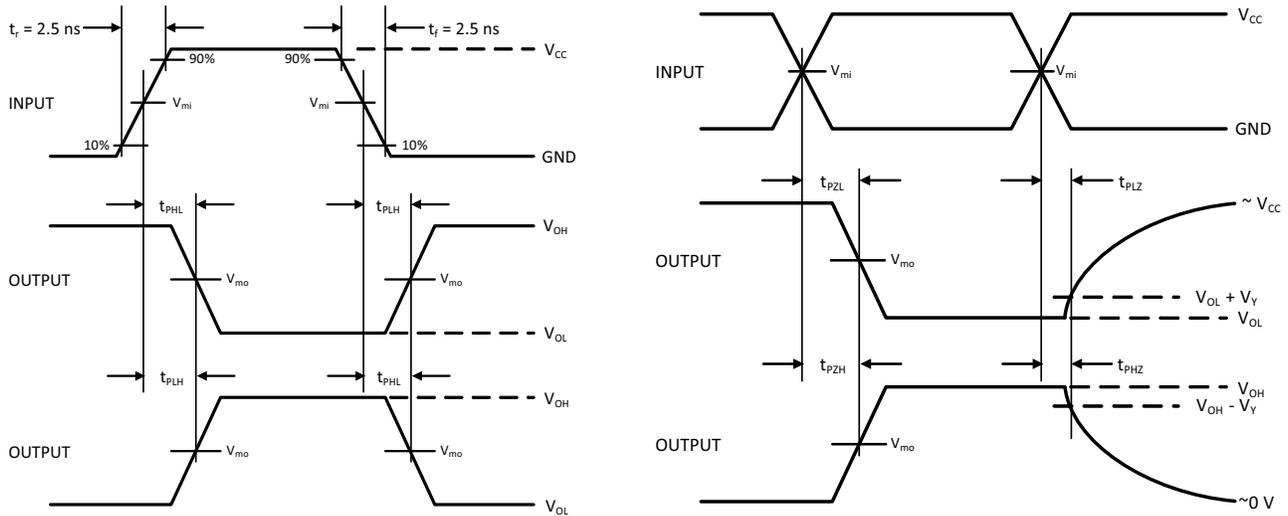
74LCX541



* C_L includes probe and jig capacitance
 R_T is Z_{OUT} of pulse generator (typically 50 Ω)
 $f = 1$ MHz

Test	Switch Position
t_{PLH} / t_{PHL}	Open
t_{PLZ} / t_{PZL}	V_{LOAD}
t_{PHZ} / t_{PZH}	GND

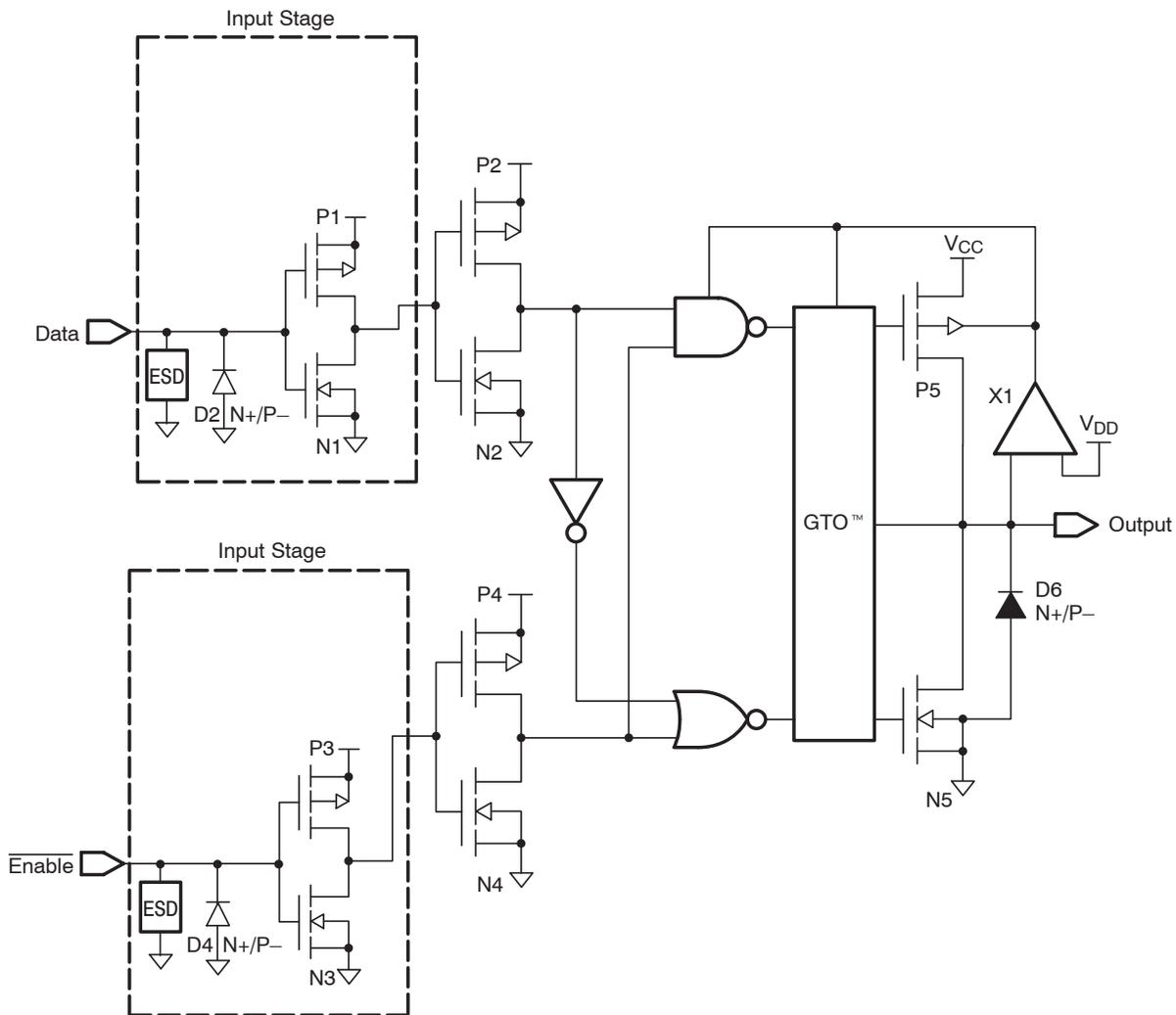
Figure 4. Test Circuit



V_{CC}, V	R_L, Ω	C_L, pF	V_{LOAD}	V_{mi}, V	V_{mo}, V	V_Y, V
1.65 to 1.95	500	30	$2 \times V_{CC}$	$V_{CC}/2$	$V_{CC}/2$	0.15
2.3 to 2.7	500	30	$2 \times V_{CC}$	$V_{CC}/2$	$V_{CC}/2$	0.15
2.7	500	50	6 V	1.5	$V_{CC}/2$	0.3
3.0 to 3.6	500	50	6 V	1.5	$V_{CC}/2$	0.3
4.5 to 4.5	500	50	$2 \times V_{CC}$	$V_{CC}/2$	$V_{CC}/2$	0.3

Figure 5. Switching Waveforms

74LCX541



**Figure 6. Schematic Diagram
(Generic for LCX Family)**

ORDERING INFORMATION

Device	Marking	Package	Shipping†
74LCX541WMX	LCX541	SOIC-20 WB	1000 / Tape & Reel
74LCX541MTC	LCX 541	TSSOP-20	75 Units / Tube
74LCX541MTCX	LCX 541	TSSOP-20	2500 / Tape & Reel

† For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

REVISION HISTORY

Revision	Description of Changes	Date
3	Truth Table correction (p.2)	2/4/2026

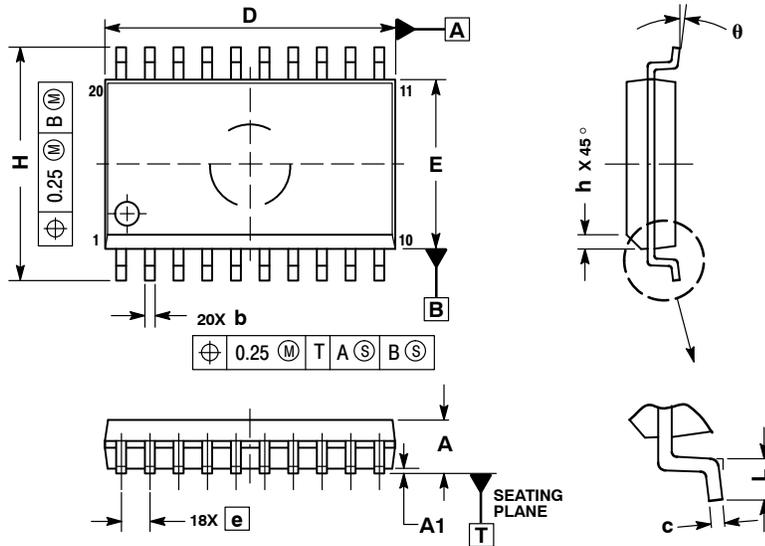
This document has undergone updates prior to the inclusion of this revision history table. The changes tracked here only reflect updates made on the noted approval dates.



SCALE 1:1

SOIC-20 WB
CASE 751D-05
ISSUE H

DATE 22 APR 2015

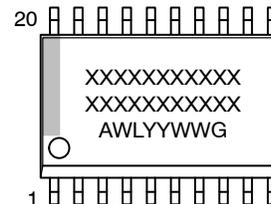


NOTES:

1. DIMENSIONS ARE IN MILLIMETERS.
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

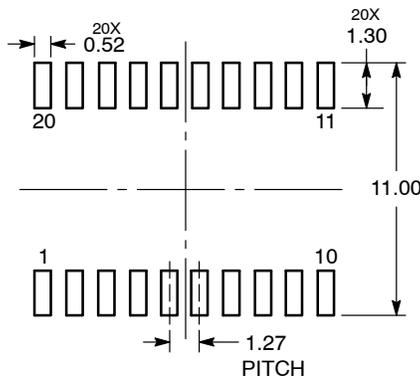
DIM	MILLIMETERS	
	MIN	MAX
A	2.35	2.65
A1	0.10	0.25
b	0.35	0.49
c	0.23	0.32
D	12.65	12.95
E	7.40	7.60
e	1.27 BSC	
H	10.05	10.55
h	0.25	0.75
L	0.50	0.90
θ	0°	7°

GENERIC
MARKING DIAGRAM*



- XXXXXX = Specific Device Code
- A = Assembly Location
- WL = Wafer Lot
- YY = Year
- WW = Work Week
- G = Pb-Free Package

RECOMMENDED
SOLDERING FOOTPRINT*



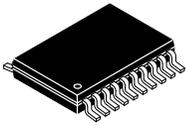
DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

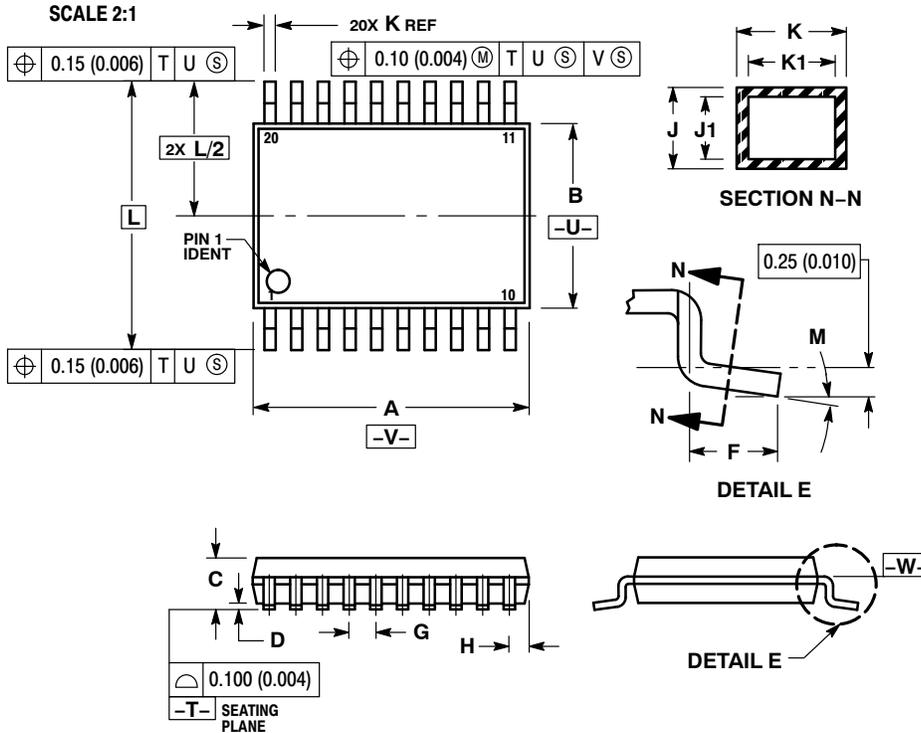
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TSSOP-20 WB
CASE 948E
ISSUE D

DATE 17 FEB 2016

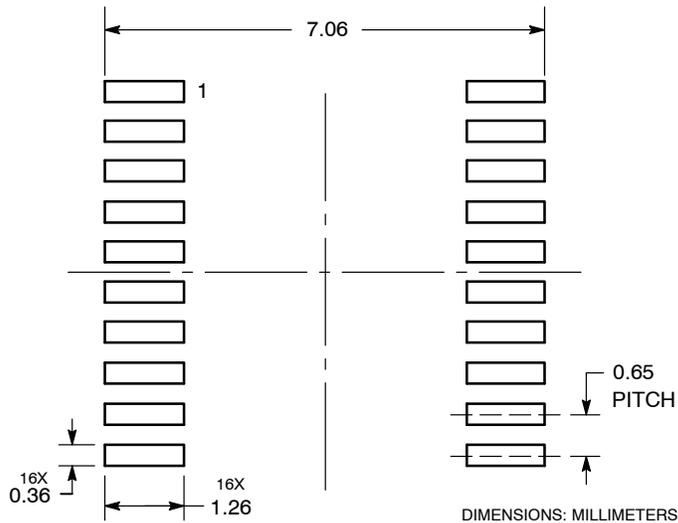


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

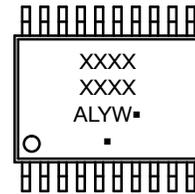
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	6.40	6.60	0.252	0.260
B	4.30	4.50	0.169	0.177
C	---	1.20	---	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.27	0.37	0.011	0.015
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0°	8°	0°	8°

RECOMMENDED
SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC
MARKING DIAGRAM*



- A = Assembly Location
- L = Wafer Lot
- Y = Year
- W = Work Week
- = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

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